# International **ICR** Rectifier

Preliminary Data Sheet PD-20603 rev. A 01/99

# **HFA08TB120S**

## HEXFRED<sup>™</sup>

#### **Features**

- · Ultrafast Recovery
- · Ultrasoft Recovery
- Very Low I<sub>RRM</sub>
- Very Low Q<sub>rr</sub>
- · Guaranteed Avalanche
- · Specified at Operating Conditions

#### **Benefits**

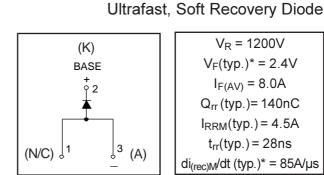
- · Reduced RFI and EMI
- · Reduced Power Loss in Diode and Switching Transistor
- · Higher Frequency Operation
- Reduced Snubbing
- · Reduced Parts Count

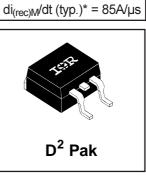
#### Description

International Rectifier's HFA08TB120S is a state of the art ultra fast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 volts and 8 amps continuous current, the HFA08TB120S is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultra fast recovery time, the HEXFRED product line features extremely low values of peak recovery current (I<sub>RRM</sub>) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA08TB120S is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

#### **Absolute Maximum Ratings**

	Parameter	Max.	Units	
VR	Cathode-to-Anode Voltage	1200	V	
I <sub>F</sub> @ T <sub>C</sub> = 100°C	Continuous Forward Current	8.0		
I <sub>FSM</sub>	Single Pulse Forward Current	130	A	
I <sub>FRM</sub>	Maximum Repetitive Forward Current	32	]	
P <sub>D</sub> @ T <sub>C</sub> = 25°C	Maximum Power Dissipation	73.5	w	
P <sub>D</sub> @ T <sub>C</sub> = 100°C	Maximum Power Dissipation	29	- vv	
TJ	Operating Junction and	55 14 1450	°C	
T <sub>STG</sub>	Storage Temperature Range	-55 to +150		





 $V_{R} = 1200V$ 

 $V_{F}(typ.)^{*} = 2.4V$ 

 $I_{F(AV)} = 8.0A$ 

Q<sub>rr</sub> (typ.)= 140nC

 $I_{RRM}(typ.) = 4.5A$ 

 $t_{rr}(typ.) = 28ns$ 

## HFA08TB120S Preliminary Data Sheet PD-20603 rev. A 01/99

# Electrical Characteristics @ $T_J = 25^{\circ}C$ (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Test Conditions	
$V_{BR}$	Cathode Anode Breakdown Voltage	1200			V	I <sub>R</sub> = 100μA	
V <sub>FM</sub>	Max Forward Voltage		2.6	3.3	v	I <sub>F</sub> = 8.0A	
			3.4	4.3		I <sub>F</sub> = 16A	
			2.4	3.1		I <sub>F</sub> = 8.0A, T <sub>J</sub> = 125°C	
I <sub>RM</sub>	Max Reverse Leakage Current		0.31	10	μA	$V_R = V_R$ Rated	
			135	1000	μΛ	$T_J$ = 125°C, $V_R$ = 0.8 x $V_R$ Rated	
CT	Junction Capacitance		11	20	pF	V <sub>R</sub> = 200V	
L <sub>S</sub>	Series Inductance		8.0		- nH	Measured lead to lead 5mm from	
	Series inductance					package body	

## Dynamic Recovery Characteristics @ $T_J = 25^{\circ}C$ (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Test Conditions		
t <sub>rr</sub>	Reverse Recovery Time		28			$I_F = 1.0A, di_f/dt = 200A/\mu s, V_R = 30V$		
t <sub>rr1</sub>			63	95	ns	T <sub>J</sub> = 25°C		
t <sub>rr2</sub>			106	160		T <sub>J</sub> = 125°C	I <sub>F</sub> = 8.0A	
I <sub>RRM1</sub>	Peak Recovery Current		4.5	8.0	Α	T <sub>J</sub> = 25°C		
I <sub>RRM2</sub>			6.2	11		T <sub>J</sub> = 125°C	V <sub>R</sub> = 200V	
Q <sub>rr1</sub>	Reverse Recovery Charge		140	380	nC	T <sub>J</sub> = 25°C		
Q <sub>rr2</sub>			335	880		T <sub>J</sub> = 125°C	di <sub>f</sub> /dt = 200A/µs	
di <sub>(rec)M</sub> /dt1	Peak Rate of Fall of Recovery Current		133		A/µs	T <sub>J</sub> = 25°C		
di <sub>(rec)M</sub> /dt2	During t <sub>b</sub>		85		μs μs	T <sub>J</sub> = 125°C		

#### **Thermal - Mechanical Characteristics**

	Parameter	Min.	Тур.	Max.	Units
T <sub>lead</sub> ①	Lead Temperature			300	°C
R <sub>thJC</sub>	Thermal Resistance, Junction to Case			1.7	K/W
R <sub>thJA</sub> ②	Thermal Resistance, Junction to Ambient			40	r\/vv
Wt	Weight		2.0		g
			0.07		(oz)

0 0.063 in. from Case (1.6mm) for 10 sec

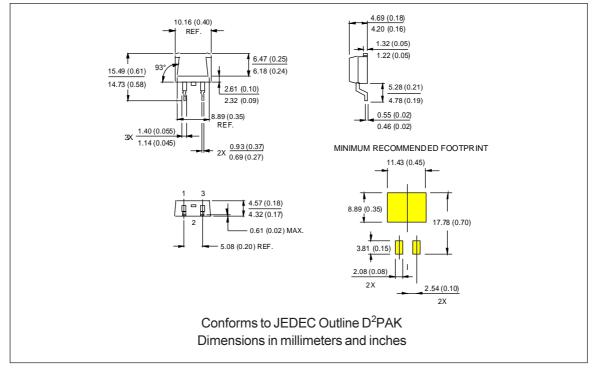
② Typical Socket Mount

# International **IOR** Rectifier

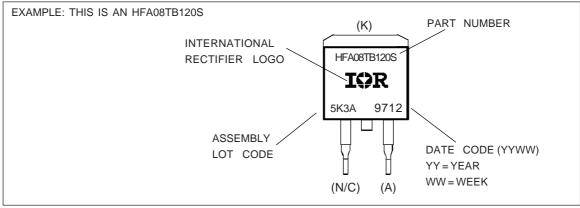
# HFA08TB120S

Preliminary Data Sheet PD-20603 rev. A 01/99

### **Outline Table**



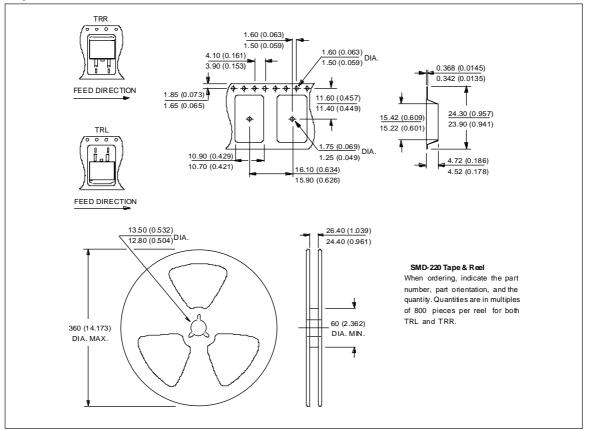
## **Part Marking Information**





# International

#### **Tape & Reel Information**



# International

 WORLDHEADQUARTERS: 233 Kansas St., El Segundo, California 90245 U.S.A. Tel: (310) 322 3331. Fax: (310) 322 3332.
EUROPEANHEADQUARTERS: Hurst Green, Oxted, Surrey RH8 9BB, U.K. Tel: ++ 44 1883 732020. Fax: ++ 44 1883 733408. IR CANADA: 15 Lincoln Court, Brampton, Markham, Ontario L6T3Z2. Tel: (905) 453 2200. Fax: (905) 475 8801.
IR GERMANY: Saalburgstrasse 157, 61350 Bad Homburg. Tel: ++ 49 6172 96590. Fax: ++ 49 6172 965933. IRITALY: Via Liguria 49, 10071 Borgaro, Torino. Tel: ++ 39 11 4510111. Fax: ++ 39 11 4510220. IR FAR EAST: K&H Bldg., 2F, 30-4 Nishi-Ikebukuro 3-Chome, Toshima-Ku, Tokyo, Japan 171. Tel: 81 3 3983 0086.
IR SOUTHEAST ASIA: 1 Kim Seng Promenade, Great World City West Tower,13-11, Singapore 237994. Tel: ++ 65 838 4630. IR TAIWAN: 16 Fl. Suite D.207, Sec. 2, Tun Haw South Road, Taipei, 10673, Taiwan. Tel: 886 2 2377 9936.

Fax-On-Demand: +44 1883 733420

http://www.irf.com